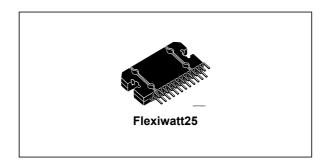


4 x 49 W quad bridge car radio amplifier

Datasheet - production data



Features

- High output power capability:
- 4 x 49 W/4 Ω max.
- 4 x 28 W/4 Ω @ 14.4V, 1 kHz, 10%
- 4 x 24 W/4 Ω @ 13.2V, 1 kHz, 10%
- · Low distortion
- Low output noise
- Standby function
- Mute function
- Automute at min. supply voltage detection
- Low external component count:

- Internally fixed gain (26dB)
- No external compensation
- No bootstrap capacitors
- Protections:
 - Output short circuit to GND, to V_S, across the load
 - Very inductive loads
 - Overrating chip temperature with soft thermal limiter
 - Load dump voltage
 - Fortuitous open GND
 - Reversed battery
 - ESD

Description

The TDA7386 is an AB class audio power amplifier, packaged in Flexiwatt 25 and designed for high end car radio applications.

Based on a fully complementary PNP/NPN configuration, the TDA7386 allows a rail to rail output voltage swing with no need of bootstrap capacitors. The extremely reduced boundary components count allows very compact sets.

Table 1. Device summary

Order code	Package	Packing
TDA7386	Flexiwatt25	Tube

Contents TDA7386

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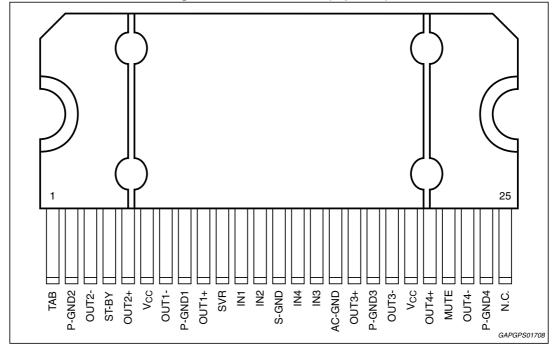
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Block and pin connection diagrams

Figure 1. Block diagram Vcc2 Vcc1 100nF _ ST-BY N.C. MUTE OUT1+ ╢ OUT1-PW-GND 0.1µF OUT2+ IN2 o OUT2-PW-GND OUT3+ IN3 o— OUT3-PW-GND OUT4+ IN4 o OUT4-PW-GND 0.1µF SVR TAB S-GND GAPGPS01707





2 Electrical specifications

2.1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Operating supply voltage	18	V
V _{CC (DC)}	DC supply voltage	28	V
V _{CC (pk)}	Peak supply voltage (t = 50 ms)	50	V
I _O	Output peak current: Repetitive (Duty Cycle 10% at f = 10 Hz) Non Repetitive (t = 100 µs)	4.5 5.5	A A
P _{tot}	Power dissipation, (T _{case} = 70 °C)	80	W
T _{amb}	Operating temperature range	– 40 to 105	°C
T _j	Junction temperature	150	°C
T _{stg}	Storage temperature	– 55 to 150	°C

2.2 Thermal data

Table 3. Thermal data

Symbol	Parameter		Value	Unit
R _{th j-case}	Thermal resistance junction-to-case	max.	1	°C/W

2.3 Electrical characteristics

 V_S = 14.4 V; f = 1 kHz; R_g = 600 Ω ; R_L = 4 Ω ; T_{amb} = 25 °C; Refer to the test and application diagram, unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
I _{q1}	Quiescent current	R _L = ∞	-	190	350	mA
V _{OS}	Output offset voltage	Play Mode	-	-	±80	mV
ΔV _{OS}	During mute on/off output offset voltage	-	-	-	±80	mV
G _v	Voltage gain	-	25	26	27	dB
ΔG_{V}	Channel gain unbalance	-	-	-	±1	dB
		THD = 10%; V _S = 13.2 V	22	24	-	W
Po	Output power	THD = 0.8%; V _S = 13.2 V	16.5	18	-	W
		THD = 10%; V _S = 14.4 V	26	28	-	W



20

μΑ

7/14

-5

Table 4. Electrical characteristics (continued)						
Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
P May output	Max.output power (1)	V _S = 14.4 V	43	45		W
P _{o max}	wax.output power V	V _S = 15.2 V	49			VV
THD	Distortion	$P_0 = 4W$	-	0.04	0.15	%
0	Output noise	"A" Weighted	-	50	70	μV
e_{No}	Output noise	Bw = 20 Hz to 20 kHz	-	70	100	μV
SVR	Supply voltage rejection	f = 100 Hz; V _r = 1V _{rms}	50	75	-	dB
f _{ch}	High cut-off frequency	P _o = 0.5 W	80	200	-	kHz
R _i	Input impedance	-	70	100	-	kΩ
	Cross tells	f = 1 kHz; Po = 4 W	60	70	-	dB
C _T	Cross talk	f = 10 kHz; Po = 4W	-	60	-	dB
	Standby current	V _{St-by} = 1.5	-	-	50	μA
I_{SB}	consumption	V _{St-by} = 0 V	-	-	20	μA
I _{pin4}	Standby pin current	V _{St-by} = 1.5 to 3.5 V	-	-	±1	μA
V _{SB out}	Standby out threshold voltage	(Amp: on)	3.5	-	-	V
V _{SB IN}	Standby in threshold voltage	(Amp: off)	-	-	1.5	V
A _M	Mute attenuation	P _{Oref} = 4 W	80	90	-	dB
V _{M out}	Mute out threshold voltage	(Amp: play)	3.5	-	-	V
$V_{M in}$	Mute in threshold voltage	(Amp: mute)	-	-	1.5	V
V	V _S automute threshold	(Amp: mute); Att \geq 80 dB; P _{Oref} = 4 Ω			6.5	V
$V_{AM in}$	v _S automute threshold	(Amp: play); Att < 0.1 dB; $P_O = 0.5 \Omega$		7.6	8.5	V
1	Muting pin current	V _{MUTE} = 1.5 V (Source current)	5	11	20	μA
I _{pin22}	ividing pin current	V _{MITE} = 3.5 V	-5	_	20	uА

 $V_{MUTE} = 3.5 V$

Table 4. Electrical characteristics (continued)

^{1.} Saturated square wave output.

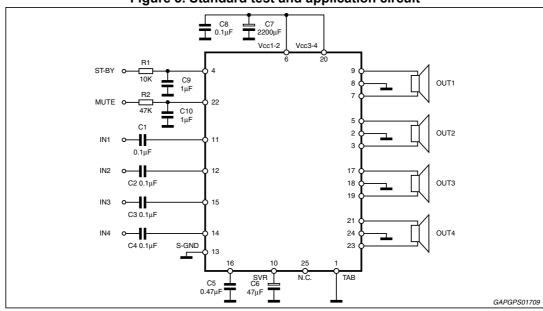


Figure 3. Standard test and application circuit

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2.4 PCB and component layout

Referred to the circuit of Figure 3.

Figure 4. Components and top copper layer

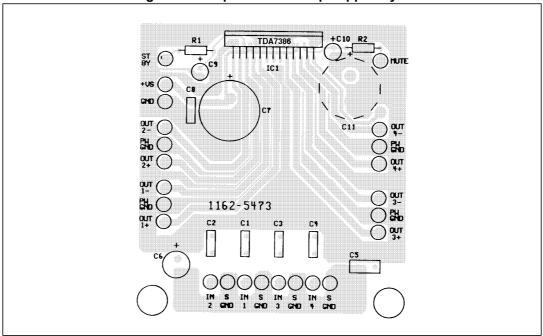
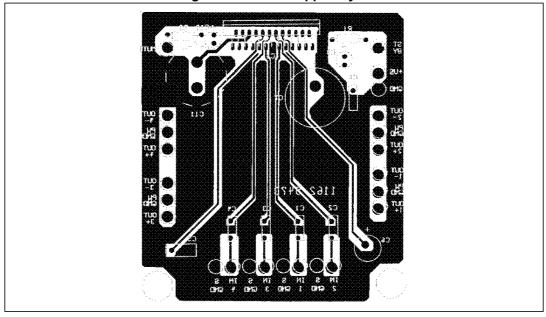


Figure 5. Bottom copper layer



2.5 Electrical characteristics curves

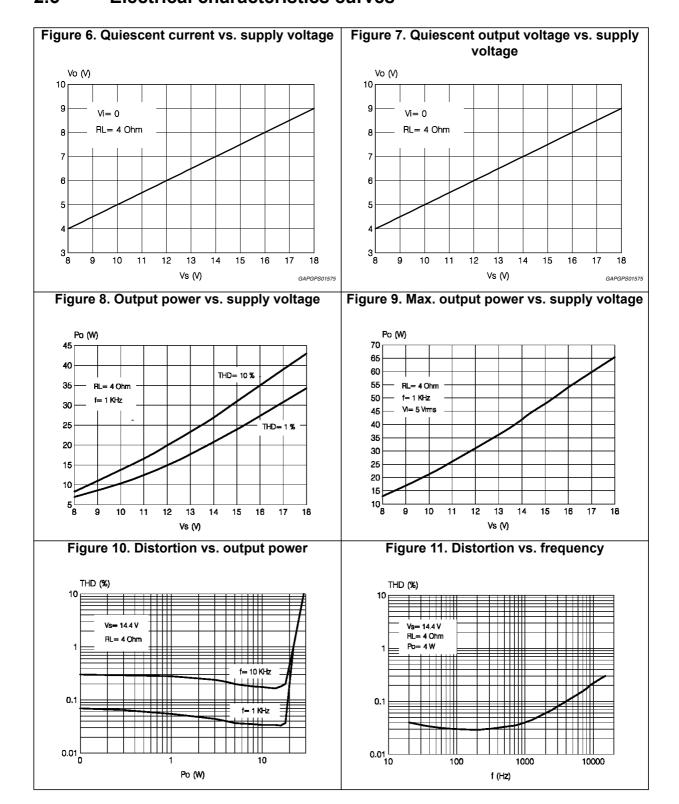


Figure 12. Supply voltage rejection vs. frequency

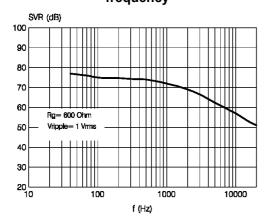


Figure 13. Crosstalk vs. frequency

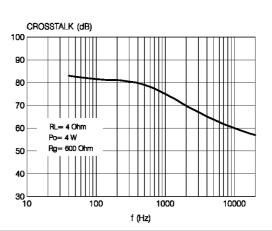


Figure 14. Output noise vs. source resistance

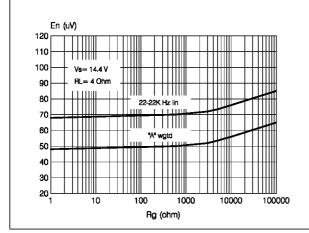
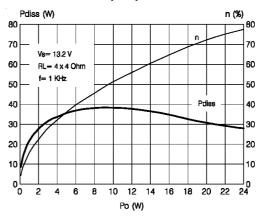


Figure 15. Power dissipation and efficiency vs. output power



TDA7386 Application hints

3 Application hints

Referred to the circuit of Figure 3.

3.1 SVR

Besides its contribution to the ripple rejection, the SVR capacitor governs the turn ON/OFF time sequence and, consequently, plays an essential role in the pop optimization during ON/OFF transients.

To conveniently serve both needs, ITS MINIMUM RECOMMENDED VALUE IS 10 µF.

3.2 Input stage

The TDA7386's inputs are ground-compatible and can stand very high input signals (±8Vpk) without any performances degradation.

If the standard value for the input capacitors (0.1 μ F) is adopted, the low frequency cut-off will amount to 16 Hz.

3.3 Standby and muting

Standby and muting facilities are both CMOS-compatible. If unused, a straight connection to Vs of their respective pins would be admissible.

Conventional/low-power transistors can be employed to drive muting and stand-by pins in absence of true CMOS ports or microprocessors. R-C cells have always to be used in order to smooth down the transitions for preventing any audible transient noises.

Since a DC current of about 10 μ A normally flows out of pin 22, the maximum allowable muting-series resistance (R₂) is 70 k Ω , which is sufficiently high to permit a muting capacitor reasonably small (about 1 μ F).

If R_2 is higher than recommended, the involved risk will be that the voltage at pin 22 may rise to above the 1.5 V threshold voltage and the device will consequently fail to turn OFF when the mute line is brought down.

About the stand-by, the time constant to be assigned in order to obtain a virtually pop-free transition has to be slower than 2.5V/ms.

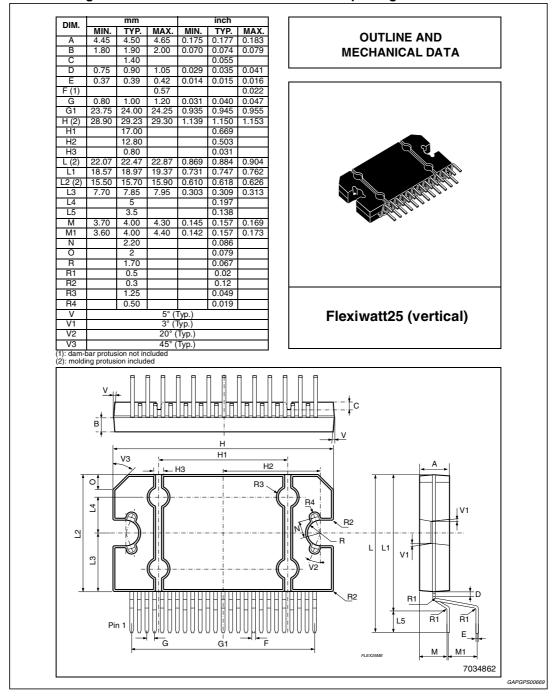
Package information TDA7386

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.

ECOPACK® is an ST trademark.

Figure 16. Flexiwatt25 mechanical data and package dimensions





TDA7386 Revision history

5 Revision history

Table 5. Document revision history

Date	Revision	Changes
24-Nov-2001	1	Initial release.
20-Dec-2007	2	Document reformatted. Modified the Features on page 1. Modified the Figure 1 and 2. Updated the Table 4: Electrical characteristics.
29-Oct-2008	3	Updated the Table 3: Thermal data on page 6.
19-Nov-2008	4	Update the Table 2: Absolute maximum ratings on page 6.
18-Sep-2013	5	Updated Features on page 1; Updated Table 4: Electrical characteristics. Updated Disclaimer.

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